## WHAT IS CLAIMED IS:

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1. A light-emitting device comprising:

a semiconductor light-emitting element using a substrate surface as a light-extracting surface; and

a mount frame on which said semiconductor light-emitting element is mounted and which has a reflecting portion for reflecting light emitted from said substrate surface;

wherein said mount frame has a swollen portion formed within said reflecting portion so that part of said substrate surface is supported by said swollen portion to thereby mount said light-emitting element on said mount frame.

- 2. A light-emitting device according to claim 1, wherein said swollen portion is formed so as to be integrated with said mount frame.
- 3. A light-emitting device according to claim 1, wherein said swollen portion is a rotationally symmetric member protruded from nearly the center of a bottom surface of said reflecting portion of said mount frame.
- 4. A light-emitting device according to claim 3, wherein said swollen portion has an inclined surface.
- 5. A light-emitting device according to claim 1,

wherein said swollen portion supports substantially the position of the center of gravity of said substrate surface.

- 6. A light-emitting device according to claim 1, wherein said swollen portion supports substantially the position of the center of gravity of a p electrode in said light-emitting element.
- 7. A light-emitting device according to claim 1,

  wherein said swollen portion supports a surface below an n
  electrode in said light-emitting element.
  - 8. A light-emitting device according to claim 1, wherein a plurality of bonding wires are connected to a p electrode in said light-emitting element.
    - 9. A light-emitting device according to claim 1, where said semiconductor light-emitting element comprises a Group III nitride compound semiconductor light-emitting element.

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